MBRT12080(R) THRU MBRT120100(R)

SCHOTTKY DIODE MODULE TYPES 120A / 80V-100V

Features

High Surge Capability
Types Up to 100V V_{RRM}
Isolation Type Package
Electrically Isolation base plate

Maximum Ratings

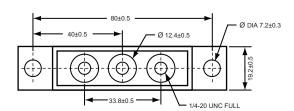
Junction Operating Temperature : -55 °C to+150 °C

Storage Temperature : -55 °C to+150 °C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
MBRT12080(R)	80V	56V	80V
MBRT12090(R)	90V	63V	90V
MBRT120100(R)	100V	70V	100V

THREE TOWER

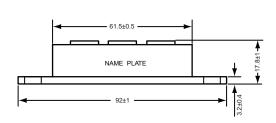
Dimensions in mm (1 mm = 0.0394")

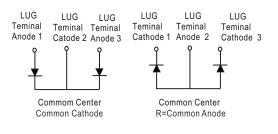


Electrcal Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current (Per pkg)	 F(AV)	120A	Tc =125°C
Peak Forward Surge Current (Per diode)	İfsm	800A	8.3ms,half sine
Maximum (Per diode) Instantaneous Forward Voltage*	V _F	0.84V	I _{FM} =60А; ТJ=25°С
Maximum Instantaneous Reverse Current At Rated DC Blocking Voltage* (Per diode)	I _R	1 mA 2 mA 6 mA	T _J = 25°C T _J =125°C T _J =150°C
Isolation Voltage	Viso	2500V	A.C. 1 minute
Maximum Thermal Resistance Junction To Case (Per diode)	Røjc	0.80°C/W	
Weight		103g	

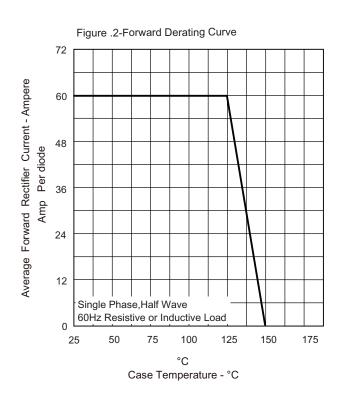
^{*}Pulse Test: Pulse Width 300 μ sec, Duty Cycle < 2%

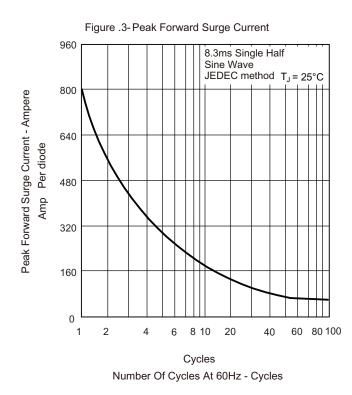


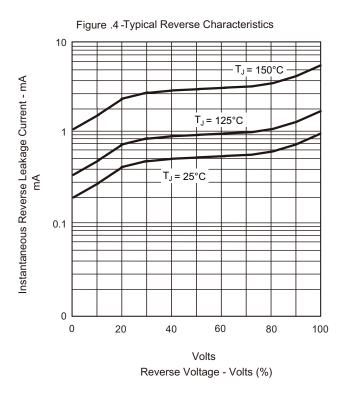


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Figure .1- Typical Forward Characteristics $T_J = 125^{\circ}C$ 1000 Instantaneous Forward Current - Ampere 600 400 200 Per diode 100 40 20 10 6 4 2 1 0.2 0 0.4 0.6 0.8 1.0 1.2 1.4 Volts Instantaneous Forward Voltage -Volts









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